Preferred Device

Power MOSFET 750 mAmps, 20 Volts

N-Channel SOT-23

These miniature surface mount MOSFETs low $R_{DS(on)}$ assure minimal power loss and conserve energy, making these devices ideal for use in space sensitive power management circuitry. Typical applications are dc-dc converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

Features

- Low R_{DS(on)} Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space
- Pb-Free Package is Available

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage		20	Vdc
Gate-to-Source Voltage - Continuous	V _{GS}	± 8.0	Vdc
Drain Current – Continuous @ T _A = 25°C – Pulsed Drain Current (t _p ≤ 10 μs)	I _D I _{DM}	750 2000	mA
Total Power Dissipation @ T _A = 25°C	PD	400	mW
Operating and Storage Temperature Range	T _J , T _{stg}	– 55 to 150	°C
Thermal Resistance - Junction-to-Ambient	$R_{\theta JA}$	300	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	TL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

olf APR



ON Semiconductor®

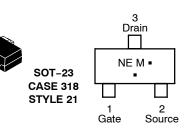
http://onsemi.com

750 mAMPS, 20 VOLTS $R_{DS(on)} = 85 \text{ m}\Omega$

N-Channel

3

MARKING DIAGRAM/ PIN ASSIGNMENT



NE = Specific Device Code

= Date Code*

М

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

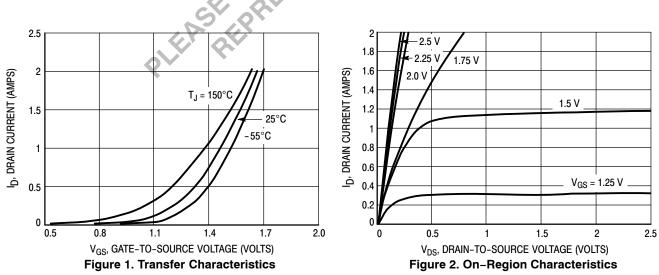
Device	Package	Shipping [†]
MGSF1N02ELT1	SOT-23	3000/Tape & Reel
MGSF1N02ELT1G	SOT-23 Pb-Free	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

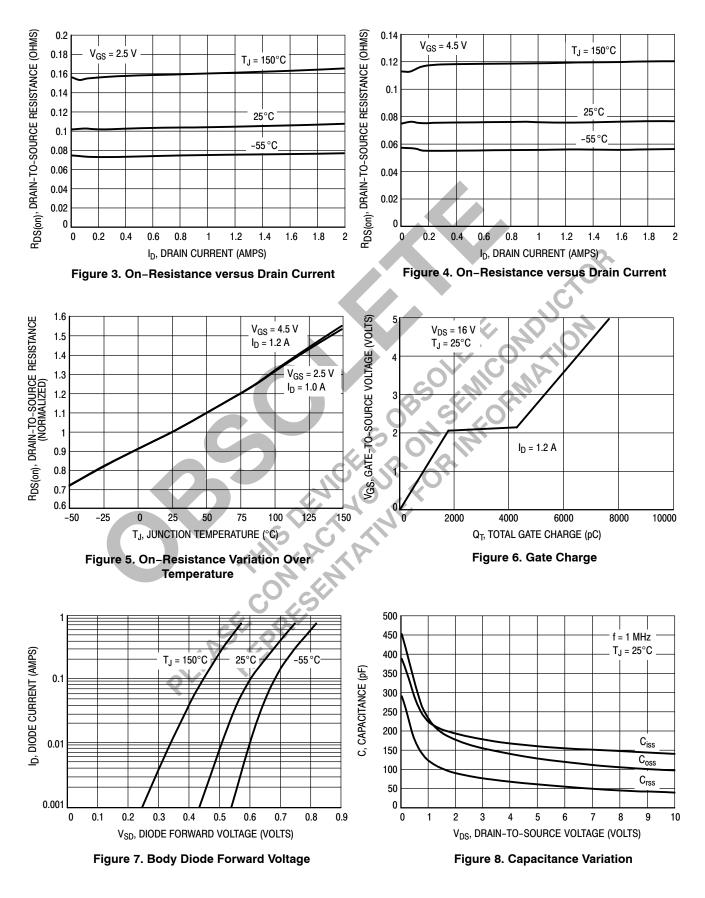
Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		·			-	
Drain-to-Source Breakdown Voltage (V_{GS} = 0 Vdc, I_D = 10 μ A)		V _{(BR)DSS}	20	_	-	Vdc
Zero Gate Voltage Drain Current (V_{DS} = 20 Vdc, V_{GS} = 0 Vdc) (V_{DS} = 20 Vdc, V_{GS} = 0 Vdc, T_J = 125°C)		I _{DSS}			1.0 10	μAdc
Gate-Source Leakage Current (V _{GS} = \pm 8.0 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	-	_	±0.1	μAdc
ON CHARACTERISTICS (Note 1)					
Gate-Source Threshold Voltage (V_{DS} = V_{GS} , I_D = 250 μ Adc)		V _{GS(th)}	0.5	-	1.0	Vdc
Static Drain-to-Source On-Resistance $(V_{GS} = 4.5 \text{ Vdc}, I_D = 1.0 \text{ A})$ $(V_{GS} = 2.5 \text{ Vdc}, I_D = 0.75 \text{ A})$		r _{DS(on)}		- -	0.085 0.115	Ω
DYNAMIC CHARACTERISTICS						
Input Capacitance	(V _{DS} = 5.0 Vdc, V _{GS} = 0 V, f = 1.0 Mhz)	C _{iss}	-	160	-	pF
Output Capacitance	(V _{DS} = 5.0 Vdc, V _{GS} = 0 V, f = 1.0 Mhz)	C _{oss}	-	130	05	
Transfer Capacitance	(V _{DG} = 5.0 Vdc, V _{GS} = 0 V, f = 1.0 Mhz)	C _{rss}	-	60	-	
SWITCHING CHARACTERISTIC	S (Note 2)			N.0		
Turn-On Delay Time		t _{d(on)}	0	6.0	-	ns
Rise Time	(V _{DD} = 5 Vdc, I _D = 1.0 Adc,	tr		26	-	
Turn-Off Delay Time	$R_L = 5 \Omega, R_G = 6 \Omega$)	t _{d(off)}	-0	117	-	
Fall Time		te	, <mark>O</mark> `	105	-	1
Total Gate Charge	$(V_{DS} = 16 \text{ Vdc}, I_D = 1.2 \text{ Adc}, V_{GS} = 4.0 \text{ Vdc})$	QT	-	6500	-	рС
SOURCE-DRAIN DIODE CHAR	ACTERISTICS					
Continuous Current		l _S	-	-	0.6	A
Pulsed Current		I _{SM}	-	-	0.75	-
Forward Voltage (Note 2) (V _{GS} =	V _{SD}	_	_	1.2	V	

Pulse Test: Pulse Width ≤300 μs, Duty Cycle ≤ 2%.
Switching characteristics are independent of operating junction temperature.



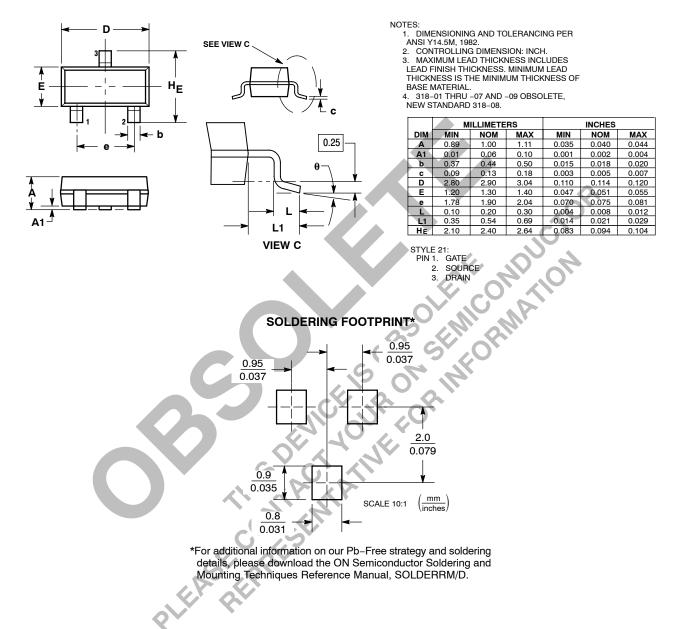
TYPICAL ELECTRICAL CHARACTERISTICS

TYPICAL ELECTRICAL CHARACTERISTICS



PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AN



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